

ICS 31.080.30

CCS L 42



**NATIONAL STANDARD OF THE
PEOPLE'S REPUBLIC OF CHINA**

GB/T 6219-1998

Replacing GB/T 6219-1986

**Semiconductor devices Discrete devices. Part 8: Field-effect
transistors. Section One. Blank detail specification for
single-gate field-effect transistors up to 5W and 1GHz**

(English Translation)

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What this standard covers

This standard specifies the development of 1GHz, the basic principles of fine specification Ocean single-gate field-effect transistor 5 W or less, to develop all the detailed specifications within this range should be consistent with the blank detail specification.

Document data

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